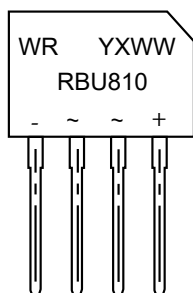


Ultrasoft Recovery Bridge



PINNING

PIN	DESCRIPTION
1	Input Pin (~)
2	Input Pin (~)
3	Output Anode (+)
4	Output Cathode (-)

Features

- Å Glass Passivated Chip Junction
- Å Reverse Voltage - 1000 V
- Å Forward Current - 8A
- Å High Surge Current Capability
- Å Designed For Surface Mount Application

Benefits

- Å Case: RBU
- Å Terminals: Solderable Per MIL-STD-750

Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

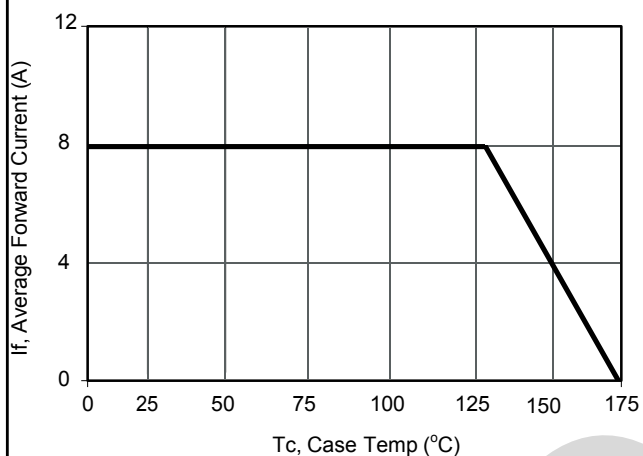
Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	WRRBU810	Units
Maximum Repetitive Peak Reverse Voltage	VRRM	1000	V
Maximum RMS voltage	VRMS	700	V
Maximum DC Blocking Voltage	VDC	1000	V
Average Rectified Output Current	Io	8.0	A
Reverse Recovery Time. IF=0.5A, IR=1A, IRR=0.25A	Trr	10	us
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	IFSM	180	A
I ² t rating for fusing (1ms< t <10ms)	I ² t	93	A ² S
Maximum Forward Voltage at 4.0 A	VF	1.0	V
Maximum DC Reverse Current @TA=25 °C at Rated DC Blocking Voltage @TA=125 °C	IR	5 100	uA
Typical Junction Capacitance (Note1)	Cj	50	pF
Operating and Storage Temperature Range	Tj, Tstg	-55 ~ +150	°C

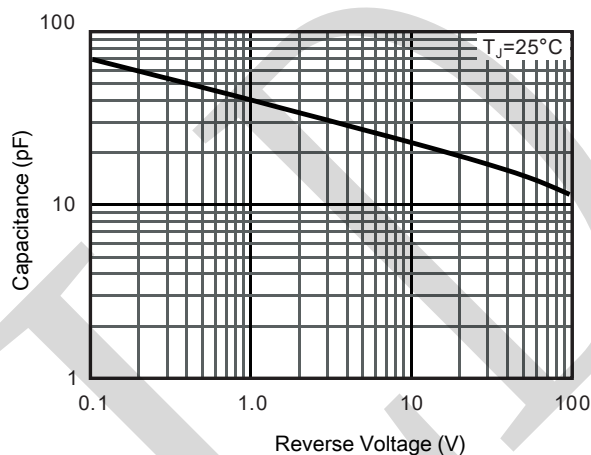
Note: 1. Measured at 1MHz and applied reverse voltage of 4 VDC.

2. Mounted on glass epoxy PC board with 4×1.5"×1.5" (3.81×3.81 cm) copper pad.

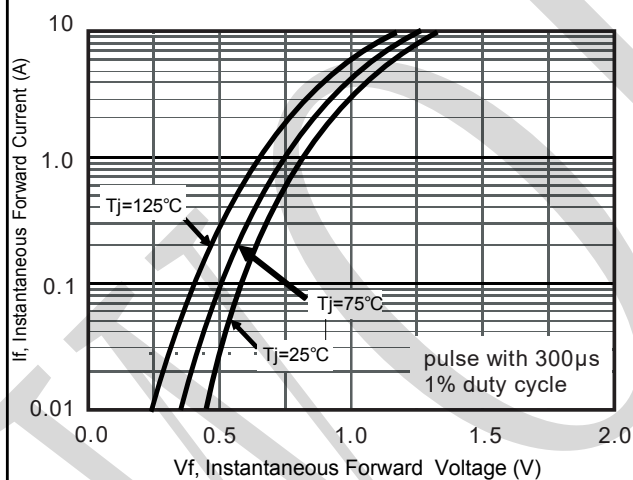
RATINGS AND CHARACTERISTICS CURVES (TA = 25 °C unless otherwise noted)



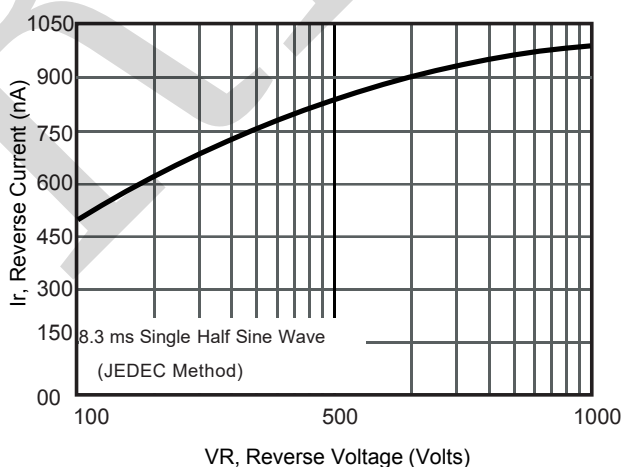
Current Derating, Case



Typical Junction Capacitance



Typical Forward Voltage



Typical Reverse Current

PACKAGE OUTLINE DIMENSIONS

